

# Power Electronics IAT1

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1. To make a signal diode suitable for high current & high voltage carrying applications with minimum losses, \_\_\_\_\_ [CO1,L2] \* 1 point

- a) a lightly doped n layer is grown between the two p & n layers
- b) a heavily doped n layer is grown between the two p & n layers
- c) a lightly doped p layer is grown between the two p & n layers
- d) a heavily doped p layer is grown between the two p & n layers



2. A diode is said to be reversed biased when the [CO1,L2] \*

1 point

- a) cathode is positive with respect to the anode
- b) anode is positive with respect to the cathode
- c) cathode is negative with respect to the anode
- d) both cathode & anode are negative

3. The peak inverse current IRR for a power diode is given by the expression [CO1,L2] \* 1 point

- a)  $IRR = t + di/dt$
- b)  $IRR = t * \log i$
- c)  $IRR = t * di/dt$
- d)  $IRR = t * \int t * i dt$

4. A p-type semiconductor material is doped with \_\_\_\_\_ impurities whereas a n-type semiconductor material is doped with \_\_\_\_\_ impurities [CO1,L2] \*

1 point

- a) acceptor, donor
- b) acceptor, acceptor
- c) donor, donor
- d) donor, acceptor

5. When a physical contact between a p-region & n-region is established which of the following is most likely to take place? [CO1,L2] \*

1 point

- a) Electrons from N-region diffuse to P-region
- b) Holes from P-region diffuse to N-region
- c) Both of the above mentioned statements are true
- d) Nothing will happen



6. Even after the forward current reduces to zero value, a practical diode continues to conduct in the reverse direction for a while due to the [CO1,L2] \* 1 point

- a) resistance of the diode
- b) high junction temperature
- c) stored charges in the depletion region
- d) none of the mentioned

7. For a p-n junction diode, the peak inverse current & the reverse recovery time are dependent on [CO1,L2] \* 1 point

- a) inverse voltage
- b) forward Voltage
- c)  $di/dt$
- d) all of the above mentioned

8. When the p-n junction diode is forward biased, the width of the depletion region \_\_\_\_\_ [CO1,L2] \* 1 point

- a) increases
- b) decreases
- c) remains Constant
- d) increases than Decreases



9. In the equilibrium state, the barrier potential across a unbiased silicon diode is \_\_\_\_\_ [CO1,L2] \* 1 point

- a) 0.3 V
- b) 0.7 V
- c) 1.3 V
- d) 0 V

10. Chopper is device which is used to convert [CO1,L2] \* 1 point

- a) variable DC to fixed DC
- b) fixed DC to AC
- c) Fixed DC to variable DC
- d) AC to AC

11. AC Voltage controller is device which converts \_\_\_\_\_ [CO1,L2] \* 1 point

- a) dc power to dc power
- b) dc power to ac power
- c) ac power to ac power
- d) ac power to dc power

12. The reverse recovery time of a diode is  $t_{rr} = 3$  microseconds, the rate of fall of diode current is  $di/dt$  is 30A/microseconds. Determine storage charge QRR. [CO1,L3] \* 2 points

- 135 micro coulomb
- 145 micro coulomb
- 125 micro coulomb
- 115 micro coulomb



13. The reverse recovery time of a diode is  $t_{rr} = 5$  microseconds, the rate of fall of diode current is  $di/dt$  is 50A/microseconds. determine peak reverse current IRR in Ampere. [CO1,L3] \* 2 points

- 150
- 250
- 350
- 200

14. In which type of diode metal-semiconductor junction is formed [CO1,L2] \* 1 point

- General purpose diode
- Fast recovery diode
- Schottky diode
- Silicon carbide diode

15. Which diode has Ultrafast switching behaviour [CO1,L2] \* 1 point

- General purpose diode
- Fast recovery diode
- Schottky diode
- Silicon carbide diode



16. A \_\_\_\_\_ is basically a diode connected across the inductive load terminals to prevent the development of high voltage across the switch. 1 point

[CO1,L2] \*

- freewheeling diode
- Fast Recovery diode
- General purpose diode
- SiC diode

17. The forward voltage drop of a power diode is  $V_D = 1.2V$ ,  $I_s = 0.0217$  micro ampere. Assuming that  $n=2$  and  $V_T = 25.7mv$ , find the diode current  $I_D$  2 points

[CO1,L3] \*

- 300 A
- 200 A
- 400 A
- 600 A

18. In ON state, when the ideal switch is on, it must have [CO1,L2] \* 1 point

- Low on state forward voltage drop
- High voltage drop
- Low Resistance
- Both a and c

19. The  $dv/dt$  of a device is limited by connecting \_\_\_\_\_ across the device 1 point

[CO1,L2] \*

- Series snubber
- Shunt snubber



20. Power converters introduce harmonics, because of [CO1,L2] \*

1 point

- Turn on
- Turn off
- Frequent switching
- Reverse bias

21. Diode is a [CO1,L2] \*

1 point

- Controlled device
- Uncontrolled device
- Semi controlled device

22. The peak inverse voltage (PIV) is applied across a diode when it is [CO1,L2] \*

1 point

- Forward-biased
- Reversed-biased
- On
- OFF

23. For the single - phase, full-wave, uncontrolled rectifier with R load, the supply voltage is 230V, 50Hz, the load resistor is 25Ω. calculate: (a) The average value of the output voltage and current. [CO1,L3] \*

2 points

- 250V, 10 A
- 207V, 8.28A
- 200V, 7A
- 210V, 9A



24. Use Question No. 23 data and find (b) The rms value of the output voltage and current. [CO1,L3] \* 2 points

- 230V, 9.2A
- 210V, 8A
- 200V, 9A
- 230V, 7A

25. Use Question No. 23 data and find (c) The dc power consumed by the load ( $P_{dc}$ ) and the average value of the ac power delivered to the load ( $P_{ac}$ ). [CO1,L3] \* 2 points

- 2.116KW, 1.714KW
- 2KW, 3KW
- 1.714KW, 2.116KW
- 2.434KW, 3.122KW

26. For single phase supply frequency of 50 Hz, ripple frequency in full wave rectifier is [CO1,L3] \* 1 point

- 50Hz
- 25Hz
- 75Hz
- 100Hz





27. For full-wave rectified sine wave, form factor is [CO1,L3] \*

1 point

- 1.11
- 2.22
- 1
- 2

28. For full-wave rectified sine wave, average value of output voltage is [CO1,L3] \*

1 point

- 0.707Vm
- 0.6366Vm
- 0.833Vm
- 0.913Vm

29. For full-wave rectified sine wave, rms value of output current is [CO1,L2] \*

1 point

- 0.707Im
- 0.6366Im
- 0.833Im
- 0.913Im

30. What is the ripple factor of Full wave Rectifier with center tapped transformer? [CO1,L2] \*

2 points

- 40.5%
- 50%
- 55%
- 48.2%



31. Give the PIV of Full wave rectifier with center tapped transformer and bridge rectifier. [CO1,L2] \* 2 points

- $V_m, 2V_m$
- $2V_m, V_m$
- $V_m, V_m$
- $2V_m, 2V_m$

32. Displacement factor is given by [CO1,L3] \* 1 point

- $\sin\phi$
- $\cos\phi$
- $\tan\phi$
- 1

33. In a DC source connected RL load through a switch, the values of  $R=10$  ohm,  $L= 220\mu\text{H}$  and the load current is 100A. Find the energy stored across the inductor. [CO1,L3] \* 2 points

- 1.1J
- 2.2J
- 3.3J
- 0



34. For the single - phase, full-wave center tapped transformer uncontrolled rectifier with R load, the supply voltage is 220V, 50Hz, the load resistor is  $50\Omega$ . calculate: (a) The average value of the output. [CO1,L3]. \*

2 points

- 2.56A
- 4.32A
- 3.96A
- 5.12A

35. For the single - phase, full-wave bridge uncontrolled rectifier with R load, the supply voltage is 220V, 50Hz, the load resistor is  $50\Omega$ . calculate: (a) The rms value of the output voltage. [CO1,L3] \*

2 points

- 220V
- 110V
- 440V
- 230V

36. For the single - phase, full-wave bridge uncontrolled rectifier with R load, the supply voltage is 220V, 50Hz, the load resistor is  $50\Omega$ . calculate PIV. [CO1,L3] \*

2 points

- 311V
- 622V
- 220V
- 440V



36. For the single - phase, full-wave uncontrolled rectifier with center tapped transformer with R load, the supply voltage is 220V, 50Hz, the load resistor is  $50\Omega$ . calculate PIV. [CO1,L3] \* 2 points

- 311V
- 622V
- 220V
- 440V

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